

PROCEEDINGS OF SPIE

High-Power Diode Laser Technology XXII

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Editors

**28–30 January 2024
San Francisco, California, United States**

Sponsored and Published by
SPIE

Volume 12867

Proceedings of SPIE 0277-786X, V. 12867

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Author(s), "Title of Paper," in *High-Power Diode Laser Technology XXII*, edited by Mark S. Zediker, Erik P. Zucker, Jenna Campbell, Proc. of SPIE 12867, Seven-digit Article CID Number (DD/MM/YYYY); (DOI URL).

ISSN: 0277-786X
ISSN: 1996-756X (electronic)

ISBN: 9781510669932
ISBN: 9781510669949 (electronic)

Published by
SPIE
P.O. Box 10, Bellingham, Washington 98227-0010 USA
Telephone +1 360 676 3290 (Pacific Time)
SPIE.org
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